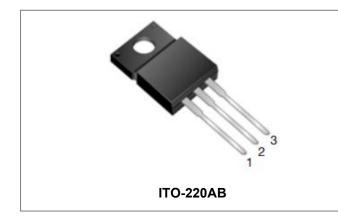


STF4080C

Technical Data Data Sheet N1755, Rev. B



STF4080C SCHOTTKY RECTIFIER



Circuit Diagram



Features

- 175 °C T_J operation
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Trench MOS Schottky technology
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	80	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=80°C, rectangular wave form	20(Per Leg) 40(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse, Tc=25°C	250	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per Leg)*	V _{F1}	@ 10A, Pulse, T _J = 25 °C @ 20A, Pulse, T _J = 25 °C	0.54 0.69	- 0.75	V
	V _{F2}	@ 10A, Pulse, TJ = 125 °C @ 20A, Pulse, TJ = 125 °C	0.52 0.65	- 0.70	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = rated V_{R,} T_J = 25 \ ^{\circ}C$	0.02	1.0	mA
	I _{R2}	$@V_R = rated V_R, T_J = 125 \circ C$	14	75	mA
Junction Capacitance	CT	@V _R = 5V, T _C = 25 °C, f _{SIG} = 1MHz	811	-	pF
RSM Isolation Voltage (t = 1.0 second, R. H. < =30%, $T_A = 25 \text{ °C}$)		Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction.	-	4500	
	V _{ISO}	Clip mounting, the epoxy body is inside the heatsink.	-	3500	V
		Screw mounting, the epoxy body is inside the heatsink.	-	1500	

* Pulse width < 300 µs, duty cycle < 2%</p>

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •



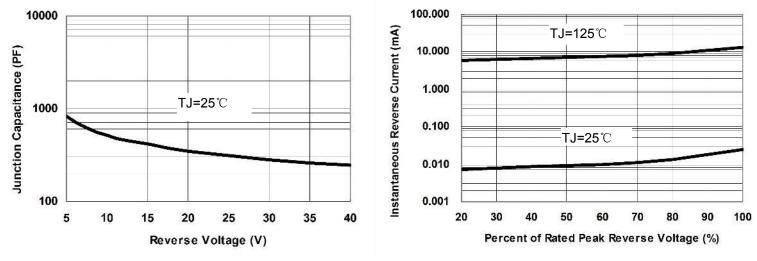




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	in DC forward mode	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case(Per Leg)	R _{θJC}	DC operation	5	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

Ratings and Characteristics Curves



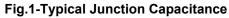


Fig.2-Typical Reverse Characteristics

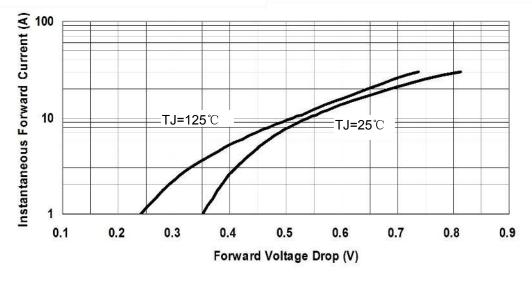


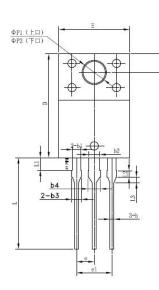
Fig.3-Typical Instantaneous Forward Voltage Characteristics

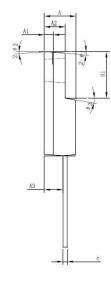
- China Germany Korea Singapore United States
 Attn://www.ama.diadaa.com aglas@ ama.diadaa.com -
- http://www.smc-diodes.com sales@ smc-diodes.com -



Mechanical Dimensions ITO-220AB

-





SYMBOL	Millimeters			
STWBOL	MIN.	TYP.	MAX.	
Α	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
b3	1.20	1.30	1.45	
b4	1.60	1.70	1.85	
С	0.50	0.60	0.75	
D	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е		2.55		
e1		5.10		
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
L1	1.60	1.80	2.00	
L2	0.80	1.00	1.20	
L3	0.60	0.80	1.00	
ΦP1(上□)	3.30	3.50	3.70	
ΦΡ2 (下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		



Marking Diagram



Where XXXXX is YYWWL

ST	= Device Type

- = Package type = Forward Current (40A)
- = Reverse Voltage (80V) = Configuration
- SSG = SSG

F 40

80

С

YΥ

ww

L

- = Year
- = Week
- = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

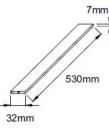
Ordering Information

Device	Package	Shipping
STF4080C	ITO-220AB (Pb-Free)	50 pcs/ tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •

Tube Specification







Technical Data Data Sheet N1755, Rev. B





DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC - Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

3- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC - Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.

4- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations.

http://www.smc-diodes.com - sales@ smc-diodes.com -